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|---|---|
|  | <h2>SI1958DH-T1-E3</h2>   |
|   | <p><b>Hersteller-Teilenummer:</b> <a href="#">SI1958DH-T1-E3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET 2N-CH 20V 1.3A SC70-6</p> <p><b>Datenblätter:</b>  <a href="#">SI1958DH-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 20383 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation.<br/>See specs for product details.</p>            |   |

### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | <a href="#">SI1958DH-T1-E3</a>                                      |
| Hersteller                                       | <a href="#">Vishay / Siliconix</a>                                  |
| Beschreibung                                     | MOSFET 2N-CH 20V 1.3A SC70-6  |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                       | 20383 pcs Stock   |
| Serie  | TrenchFET®  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Leistung - max                                   | 1.25W   |
| Verpackung / Gehäuse                             | 6-TSSOP, SC-88, SOT-363   |
| Supplier Device-Gehäuse                          | SC-70-6 (SOT-363)   |
| Typ FET  | 2 N-Channel (Dual)  |
| FET-Merkmal                                      | Logic Level Gate  |
| Drain-Source-Spannung (Vdss)                     | 20V   |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 1.3A  |
| Rds On (Max) @ Id, Vgs                           | 205 mOhm @ 1.3A, 4.5V   |
| VGS (th) (Max) @ Id                              | 1.6V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                     | 3.8nC @ 10V   |
| Eingabekapazität (Ciss) (Max) @ Vds              | 105pF @ 10V   |
| Verpackung                                       | Tape & Reel (TR)  |






SI1958DH-T1-E3 ist neu im Original, Suche SI1958DH-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1958DH-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1958DH-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|  |  |   |   |
|--|--|---|---|
| <br><b>SI1965DH-E3</b><br>VISHAY<br>SI1965DH-E3 VISHAY                          | <br><b>SI1926DL-T1-E3</b><br>Electro-Films (EFI) / Vishay<br>MOSFET 2N-CH 60V 0.37A SC-70-6 | <br><b>SI1958DH-T1-E3</b><br>Electro-Films (EFI) / Vishay<br>MOSFET 2N-CH 20V 1.3A SC70-6 | <br><b>SI1958DH-T1-GE3</b><br>VISHAY<br>VISHAY SOT363            |
| <br><b>SI1965DH-T1-E3</b><br>Vishay / Siliconix<br>MOSFET 2P-CH 12V 1.3A SC70-6 | <br><b>SI1926DL-T1-GE3</b><br>Electro-Films (EFI) / Vishay<br>MOSFET 2N-CH 60V 0.37A SOT363 | <br><b>SI1926DL-T1-E3</b><br>Vishay / Siliconix<br>MOSFET 2N-CH 60V 0.37A SC-70-6         | <br><b>Si1965DH</b><br>Vishay Precision Group<br>Si1965DH Vishay |

### heiße Teile

Mehr

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|--|--|--|---|--|
|  SI1905DL-T1      |  SI1905DL-T1-E3   |  SI1905DL-T1-E3     |  SI1905DL-T1-GE3 |  SI1906DL-T1      |
|  SI1912EDH        |  SI1912EDH-T1     |  SI1912EDH-T1-E3    |  SI1912EDH-T1-E3 |  SI1912EDH-T1-GE3 |
|  SI1913DH-T1-E3   |  SI1913DH-T1-E3   |  SI1913DH-T1-GE3    |  SI1913EDH-T1    |  SI1913EDH-T1-E3  |
|  SI1913EDH-T1-E3  |  SI1913EDH-T1-GE3 |  SI1917EDH-T1       |  SI1917EDH-T1-E3 |  SI1917EDH-T1-E3  |
|  SI1917EDH-T1-GE3 |  SI1922EDH-T1-GE3 |  SI1922EDH-T1-GE3   |  SI1926DL-T1-E3  |  SI1926DL-T1-E3   |
|  SI1926DL-T1-GE3  |  SI1926DL-T1-GE3  |  SI1958DH-T1-E3     |  SI1965DH-E3     |  SI1965DH-T1-E3   |
|  SI1965DH-T1-E3   |  SI1965DH-T1-GE3  |  SI1965DH-T1-GE3    |  SI1967DH-T1-E3  |  SI1967DH-T1-E3   |
|  SI1967DH-T1-GE3  |  SI1967DH-T1-GE3  |  SI1969DH-E3        |  SI1970DH-T1-GE3 |  SI1970DH-T1-GE3  |
|  SI1972DH-T1      |  SI1972DH-T1-E3   |  SI1972DH-T1-E3     |  SI1972DH-T1-GE  |  SI1972DH-T1-GE3  |
|  SI1972DH-T1-GE3  |  SI1973DH-E3      |  SI1983DT-285-T1-E3 |  SI1988DH-T1-GE3 |  SI1988DH-T1-GE3  |

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